

4N38M, H11D1M, H11D2M, H11D3M, MOC8204M High Voltage Phototransistor Optocouplers

Features

- High voltage:
 - MOC8204M, BV_{CER} = 400V
 - H11D1M, H11D2M, BV_{CER} = 300V
 - H11D3M, BV_{CER} = 200V
- High isolation voltage:
 - 7500 V_{AC} peak, 1 second
- Underwriters Laboratory (UL) recognized File # E90700, Volume 2
- IEC 60747-5-2 approved (ordering option V)

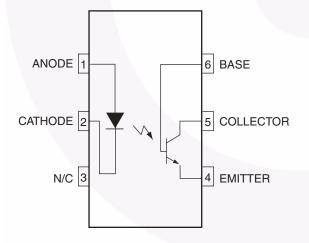
Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs
- Appliance sensor systems
- Industrial controls

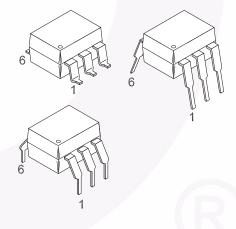
General Description

The 4N38M, H11DXM and MOC8204M are phototransistor-type optically coupled optoisolators. A gallium arsenide infrared emitting diode is coupled with a high voltage NPN silicon phototransistor. The device is supplied in a standard plastic six-pin dual-in-line package.

Schematic



Package Outlines



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter Device		Value	Units
TOTAL DEV	TICE			
T _{STG}	Storage Temperature	All	-40 to +150	°C
T _{OPR}	Operating Temperature	All	-40 to +100	°C
T _{SOL}	Lead Solder Temperature (Wave Solder)	All	260 for 10 sec	°C
P_{D}	Total Device Power Dissipation @ T _A = 25°C	All	260	mW
	Derate Above 25°C		3.5	mW/°C
EMITTER				
I _F	Forward DC Current ⁽¹⁾	All	80	mA
V _R	Reverse Input Voltage ⁽¹⁾	All	6.0	V
I _F (pk)	Forward Current – Peak (1µs pulse, 300pps) ⁽¹⁾	All	3.0	А
P_{D}	LED Power Dissipation @ T _A = 25°C ⁽¹⁾	All	150	mW
	Derate Above 25°C		1.41	mW/°C
DETECTOR				
P_{D}	Power Dissipation @ T _A = 25°C	All	300	mW
	Derate linearly above 25°C		4.0	mW/°C
V _{CER}	Collector to Emitter Voltage ⁽¹⁾	MOC8204M	400	V
		H11D1M, H11D2M	300	
		H11D3M	200	
		4N38M	80	
V _{CBO}	Collector Base Voltage ⁽¹⁾	MOC8204M	400	V
		H11D1M, H11D2M	300	
		H11D3M	200	
		4N38M	80	
V _{ECO}	Emitter to Collector Voltage ⁽¹⁾	H11D1M, H11D2M, H11D3M, MOC8204M	7	V
I _C	Collector Current (Continuous)	All	100	mA

Note:

1. Parameters meet or exceed JEDEC registered data (for 4N38M only).

Electrical Characteristics (T_A = 25°C unless otherwise specified.)

Individual Component Characteristics

Symbol	Characteristic	Test Conditions	Device	Min.	Typ.*	Max.	Unit
EMITTER	-			'		•	-
V _F	Forward Voltage ⁽²⁾	I _F = 10mA	All		1.15	1.5	V
$\frac{\Delta V_F}{\Delta T_A}$	Forward Voltage Temp. Coefficient		All		-1.8		mV/°C
BV_R	Reverse Breakdown Voltage	I _R = 10μA	All	6	25		V
CJ	Junction Capacitance	$V_F = 0V, f = 1MHz$	All		50		pF
		$V_F = 1V, f = 1MHz$			65		pF
I _R	Reverse Leakage Current ⁽²⁾	V _R = 6V	All		0.05	10	μA
DETECTO	R					•	-
BV _{CER}	Breakdown Voltage	$R_{BE} = 1M\Omega, I_{C} = 1.0mA, I_{F} = 0$	MOC8204M	400			V
	Collector to Emitter ⁽²⁾		H11D1M/2M	300			
			H11D3M	200			
BV _{CEO}		No RBE, I _C = 1.0mA	4N38M	80			
BV _{CBO}	Collector to Base ⁽²⁾	$I_C = 100 \mu A, I_F = 0$	MOC8204M	400			V
			H11D1M/2M	300			
			H11D3M	200			
			4N38M	80	\		
BV _{EBO}	Emitter to Base	$I_E = 100 \mu A, I_F = 0$	4N38M	7			V
BV _{ECO}	Emitter to Collector	$I_E = 100 \mu A, I_F = 0$	All	7	10		V
I _{CER}	Leakage Current Collector to Emitter ⁽²⁾ ($R_{BE} = 1M\Omega$)	$V_{CE} = 300V, I_F = 0, T_A = 25^{\circ}C$	MOC8204M			100	nA
		$V_{CE} = 300V, I_F = 0, T_A = 100^{\circ}C$				250	μA
		V _{CE} = 200V, I _F = 0, T _A = 25°C	H11D1M/2M			100	nA
		V _{CE} = 200V, I _F = 0, T _A = 100°C				250	μA
		V _{CE} = 100V, I _F = 0, T _A = 25°C	H11D3M			100	nA
		V _{CE} = 100V, I _F = 0, T _A = 100°C				250	μA
I _{CEO}		No R _{BE} , V_{CE} = 60V, I_F = 0, T_A = 25°C	4N38M			50	nA

Transfer Characteristics ($T_A = 25$ °C Unless otherwise specified.)

Symbol	Characteristics	Test Conditions	Device	Min.	Тур.*	Max.	Units
EMITTER							
CTR	Current Transfer Ratio, Collector to	I_F = 10mA, V_{CE} = 10V, R_{BE} = 1M Ω	H11D1M/2M/3M, MOC8204M	2 (20)			mA (%)
	Emitter	I _F = 10mA, V _{CE} = 10V	4N38M	2 (20)			
V _{CE(SAT)}	Saturation Voltage ⁽²⁾	I_F = 10mA, I_C = 0.5mA, R_{BE} = 1M Ω	H11D1M/2M/3M, MOC8204M		0.1	0.40	V
		I _F = 20mA, I _C = 4mA	4N38M			1.0	
SWITCHING TIMES							
t _{ON}	Non-Saturated Turn-on Time	V_{CE} = 10V, I_{CE} = 2mA, R_L = 100 Ω	All		5		μs
t _{OFF}	Turn-off Time		All		5		μs

^{*}All Typical values at $T_A = 25$ °C

Note:

2. Parameters meet or exceed JEDEC registered data (for 4N38M only).

DC Electrical Characteristics (Continued) (T_A = 25°C unless otherwise specified.)

Isolation Characteristics

Symbol	Characteristic	Test Conditions	Device	Min.	Тур.*	Max.	Units
V _{ISO}	Isolation Voltage	f = 60Hz, t = 1 sec.	All	7500			V _{AC} PEAK
R _{ISO}	Isolation Resistance	V _{I-O} = 500 VDC	All	10 ¹¹			Ω
C _{ISO}	Isolation Capacitance	f = 1MHz	All		0.2		pF

^{*}All Typical values at $T_A = 25$ °C

Typical Performance Curves

Fig. 2 Normalized Output Characteristics

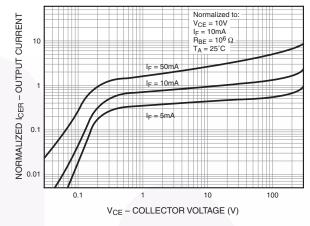


Fig. 3 Normalized Output Current vs. LED Input Current

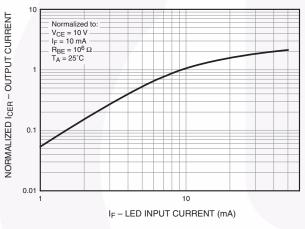


Fig. 4 Normalized Output Current vs. Temperature

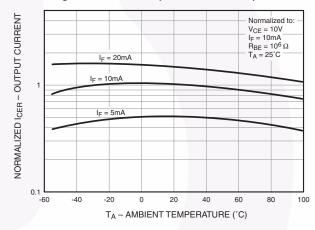


Fig. 5 Normalized Dark Current vs. Ambient Temperature

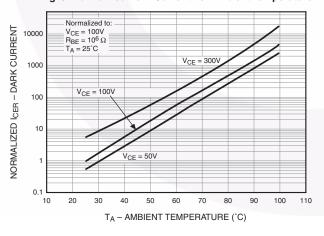
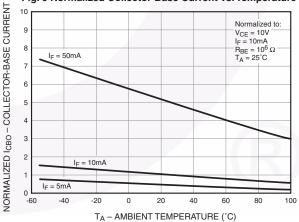
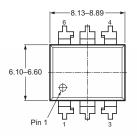


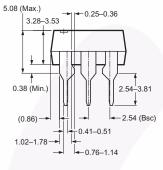
Fig. 6 Normalized Collector-Base Current vs. Temperature

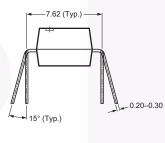


Package Dimensions

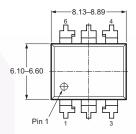
Through Hole

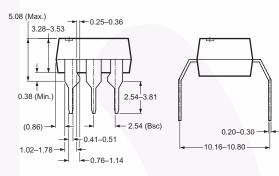




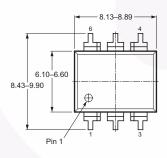


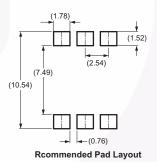
0.4" Lead Spacing

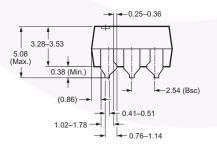


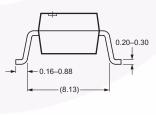


Surface Mount







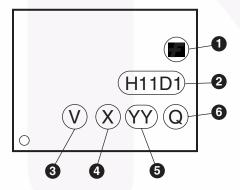


Note: All dimensions in mm.

Ordering Information

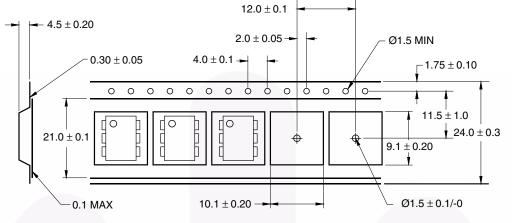
Option	Order Entry Identifier (Example)	Description
No option	H11D1M	Standard Through Hole Device (50 units per tube)
S	H11D1SM	Surface Mount Lead Bend
SR2	H11D1SR2M	Surface Mount; Tape and Reel
Т	H11D1TM	0.4" Lead Spacing
V	H11D1VM	VDE 0884
TV	H11D1TVM	VDE 0884, 0.4" Lead Spacing
SV	H11D1SVM	VDE 0884, Surface Mount
SR2V	H11D1SR2VM	VDE 0884, Surface Mount, Tape and Reel

Marking Information



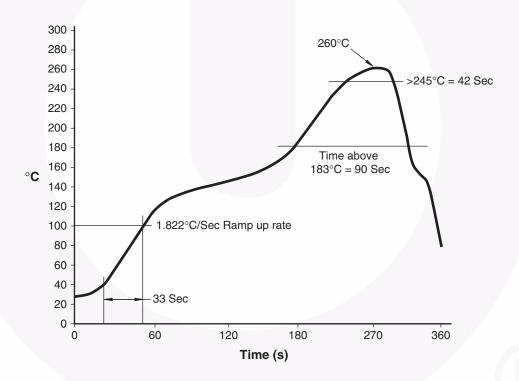
Definitions				
1	Fairchild logo			
2	Device number			
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)			
4	One digit year code, e.g., '7'			
5	Two digit work week ranging from '01' to '53'			
6	Assembly package code			

Carrier Tape Specification



User Direction of Feed ----

Reflow Profile







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Green FPS™ e-Series™

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